Equipment Information Sheet

Plasma-Therm Takachi ALE

Manager: Jeremy Clark607-254-6487Calls to staff phones will be automatically forwarded to
their cell phones during accessible hours. At other times
leave a message or send them an email.

SAFETY

• HBr, Cl2, and BCl3 gases are used

USAGE RESTRICTIONS

- DO NOT modify recipes without staff permission
- Must remain in cleanroom during plasma processing

SCHEDULING/SIGN-UP RESTRICTIONS MATERIALS COMPATIBILITY CATEGORY

Minimum Tool Time: 15 minutes

Tool Category 2: Silicon Based Substrates and Select Refractory Metals

Allowed	Not Allowed
Tool category 1/1E materials	No Glass Substrates
Silicon Based Materials only	No CNF Class A or Class B metals and oxides/compounds of (exposed or buried) (ie Magnesium, Zinc, Barium, Calcium)
Si, SiC, SiO ₂ substrates	
All Furnace grown or deposited films	
PECVD Films	No Gold, Silver or Copper (Exposed or buried)
ALD dieletric films	No High Vapor pressure materials
CNF Refractory Metals (ie Al, Ti,Ta,W,Pt,Mo,Cr,Ni)	No III/V Compound Semiconductors
Nitrides and Oxides of above metals	No Organic/Biology Molecules prepared-with or without Salt buffers
Cured organics and baked Photoresist	

High Vapor Pressure Metals and Compounds are materials that have a vapor pressure above 1e-6 Torr at 400 C.

Additional Material Restrictions and Exceptions

Select III/V materials allowed- ask staff before proceeding!

Last Updated: 08/05/2024